

# SILICON SWITCHING DIODE 1SS303

## HIGH SPEED SWITCHING SILICON EPITAXIAL DOUBLE DIODE : COMMON ANODE

#### **FEATURES**

- Low capacitance: Ct = 2.5 pF TYP.
- High speed switching: trr = 4.0 ns MAX.
- Wide applications including switching, limitter, clipper.
- Double diode configuration assures economical use.

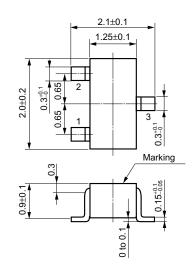
#### **ABSOLUTE MAXIMUM RATINGS**

Maximum Voltages and Currents (T<sub>A</sub> = 25°C)

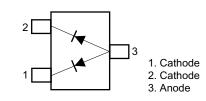
	Peak Reverse Voltage	$V_{RM}$	75	V		
	DC Reverse Voltage	$V_{R}$	50	V		
	Surge Current (1 $\mu$ s) Note	IFSM	6.0	Α		
	Surge Current (1 µs)	<b>I</b> FSM	4.0	Α		
	Peak Forward Current Note	Iғм	450	mA		
	Peak Forward Current	Іғм	300	mA		
	Average Rectified Current Note	lo	150	mA		
	Average Rectified Current	lo	100	mA		
ſ	Maximum Temperatures					
	Junction Temperature	$T_j$	150	°C		
	Storage Temperature Range	Tstg	-55 to + 150	°C		
Thermal Resistance						
	Junction to Ambient Note	Rth(j-a)	1.0	°C/mW		
	Junction to Ambient	Rth(j-a)	0.85	°C/mW		

Note Both diodes loaded simultaneously.

#### PACKAGE DIMENSIONS (Unit: mm)



#### **CONNECTION DIAGRAM (Top View)**



Marking: A4

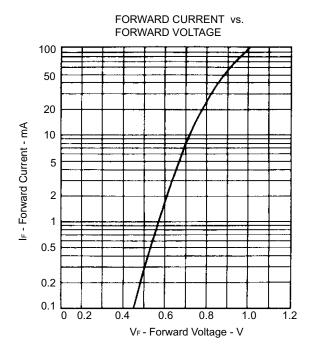
#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

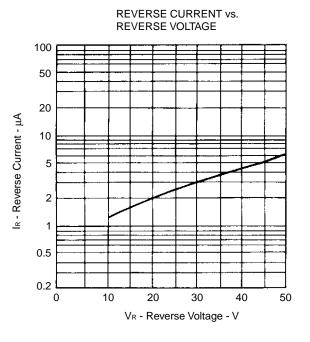
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Forward Voltage	V <sub>F1</sub>	IF = 10 mA		0.72	1.0	V
	V <sub>F2</sub>	IF = 50 mA		0.88	1.1	V
	V <sub>F3</sub>	IF = 100 mA		1.0	1.2	V
Reverse Current	<b>I</b> R	V <sub>R</sub> = 50 V			0.1	μΑ
Capacitance	Ct	V <sub>R</sub> = 0 V, f = 1.0 MHz		2.5	4.0	pF
Reverse Recovery Time	trr	See Test Circuit.			4.0	ns

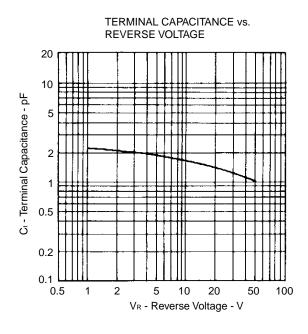
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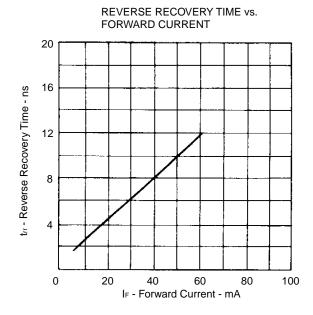


#### TYPICAL ELECTRICAL CURVES (TA = 25°C)



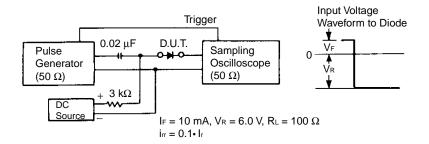


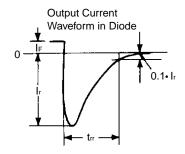






### REVERSE RECOVERY TIME (trr) TEST CIRCUIT





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